

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

Appln. No: To Be Assigned  
Applicant: Hidetoshi Ishida, et al.  
Filed: Herewith  
Title: ETCHANT AND METHOD FOR FABRICATING A SEMICONDUCTOR DEVICE  
USING THE SAME  
TC/A.U.: To Be Assigned  
Examiner: To Be Assigned  
Confirmation No.: To Be Assigned  
Docket No.: YAO-3990US3

**PRELIMINARY AMENDMENT**

Mail Stop Patent Application  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Sir:

Prior to examination, please amend the above-identified application as follows:

- ☒ **Amendments to the Specification** begin on page 2 of this paper.
- ☒ **Amendments to the Claims** are reflected in the listing of claims which begins on page 3 of this paper.
- ☐ **Amendments to the Drawings** begin on page       of this paper and include an attached replacement sheet(s).
- ☐ **Amendments to the Abstract** are on page       of this paper. A clean version of the Abstract is on page       of this paper.
- ☒ **Remarks/Arguments** begin on page 4 of this paper.